



SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		LIMITS			UNIT
				MIN.	TYP. ^a	MAX.	
Static							
Drain-Source Breakdown Voltage	V _{DS}	V _{DS} = 0 V, I _D = 10 μA		60	75	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 1 mA		0.8	1.7	2	
		T _C = - 55 °C		-	-	2.5	
		T _C = 125 °C		0.3	-	-	
Gate-Body Leakage	I _{GSS}	V _{GS} = ± 20 V	V _{DS} = 0 V	-	-	± 100	nA
			T _C = 125 °C	-	-	± 500	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 48 V	-	-	1	μA
			T _C = 125 °C	-	-	100	
On-State Drain Current	I _{D(on)}	V _{GS} = 10 V	V _{DS} = 10 V	-	2	-	A
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 5 V	I _D = 0.3 A	-	2	5	Ω
		V _{GS} = 10 V	I _D = 1 A	-	1.3	3	
			T _C = 125 °C	-	2.4	5.6	
Forward Transconductance ^b	g _{fs}	V _{DS} = 7.5 V, I _D = 0.525 A		170	350	-	mS
Diode Forward Voltage	V _{SD}	I _S = 0.99 A, V _{GS} = 0 V		0.7	0.8	1.6	V
Dynamic							
Input Capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 25 V, f = 1 MHz	-	35	50	pF
Output Capacitance	C _{oss}			-	25	40	
Reverse Transfer Capacitance	C _{rss}			-	7	10	
Drain-Source Capacitance	C _{ds}			-	30	-	
Switching ^c							
Turn-On Time	t _{ON}	V _{DD} = 25 V, R _L = 23 Ω I _D ≅ 1 A, V _{GEN} = 10 V, R _g = 25 Ω		-	8	10	ns
Turn-Off Time	t _{OFF}			-	8.5	10	

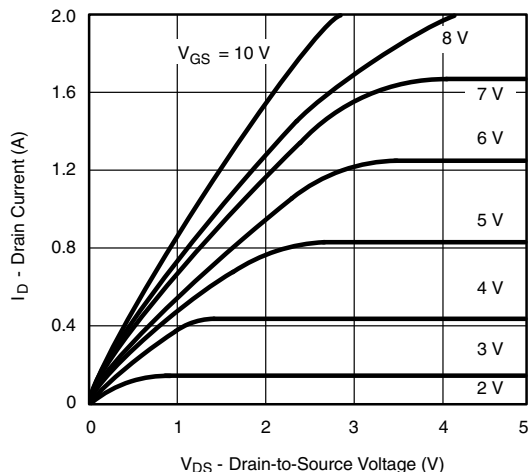
Notes

- FOR DESIGN AID ONLY, not subject to production testing.
- Pulse test: $PW \leq 300\text{ }\mu\text{s}$ duty cycle $\leq 2\%$.
- Switching time is essentially independent of operating temperature.

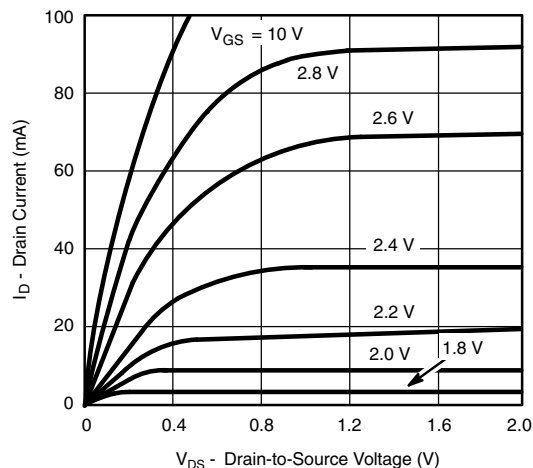
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



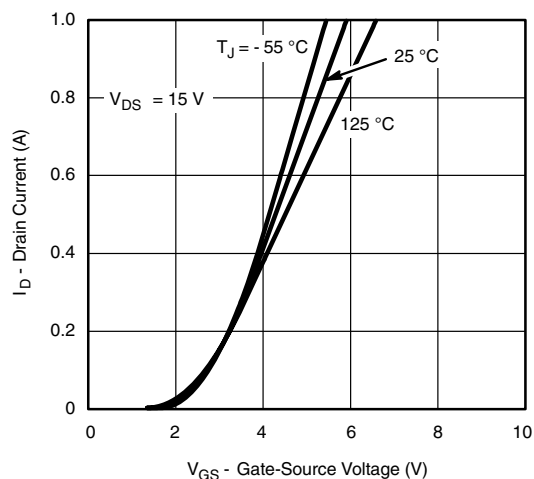
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



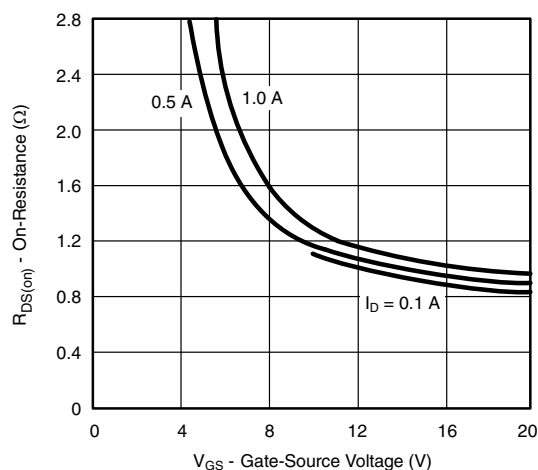
Ohmic Region Characteristics



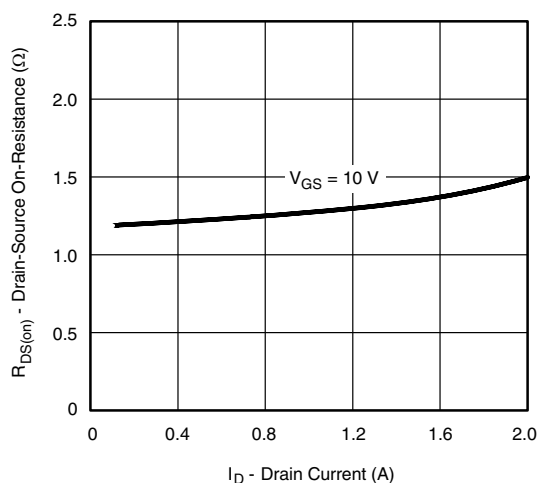
Output Characteristics for Low Gate Drive



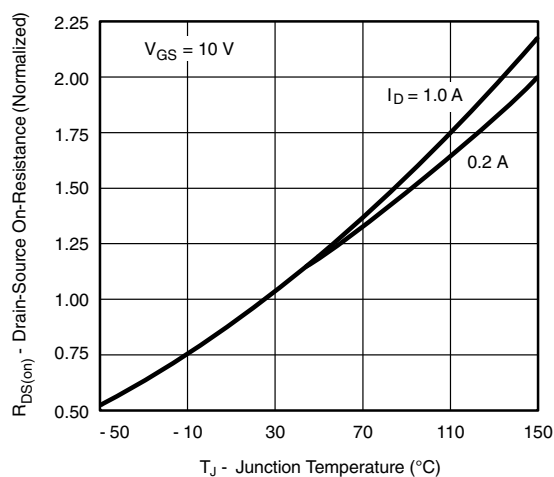
Transfer Characteristics



On-Resistance vs. Gate-to-Source Voltage



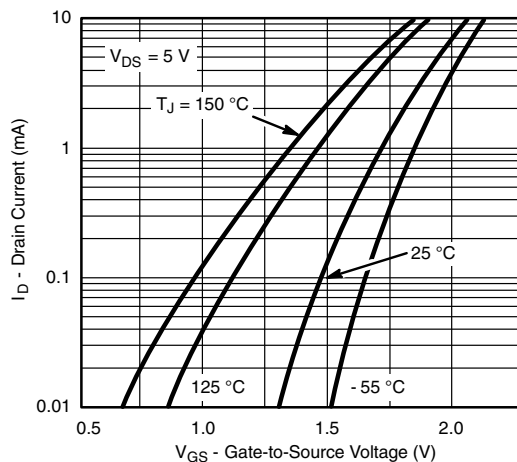
On-Resistance vs. Drain Current



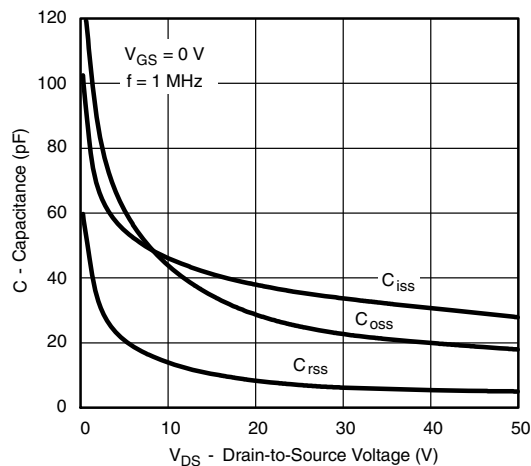
Normalized On-Resistance vs. Junction Temperature



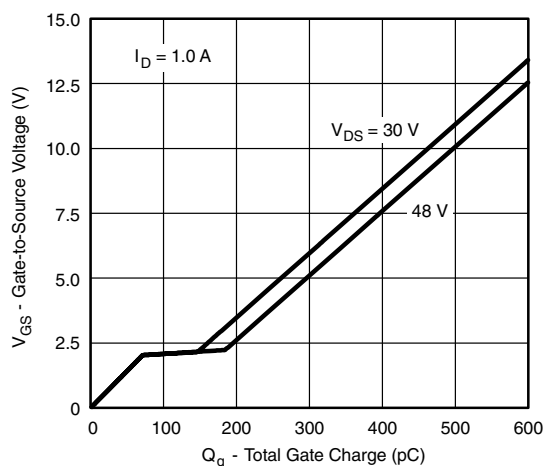
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



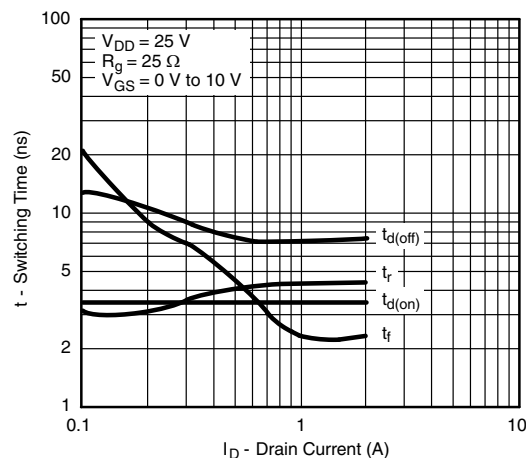
Threshold Region



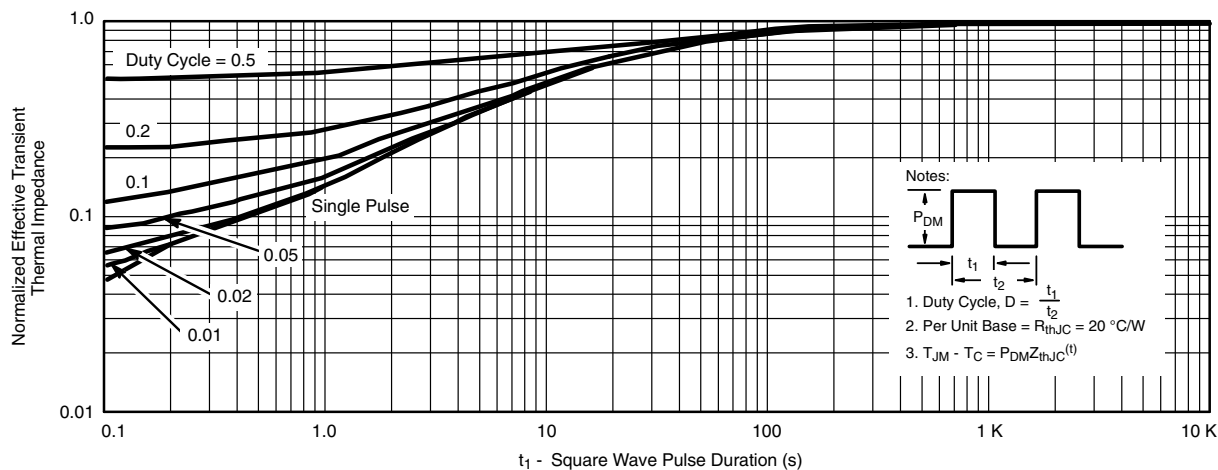
Capacitance



Gate Charge



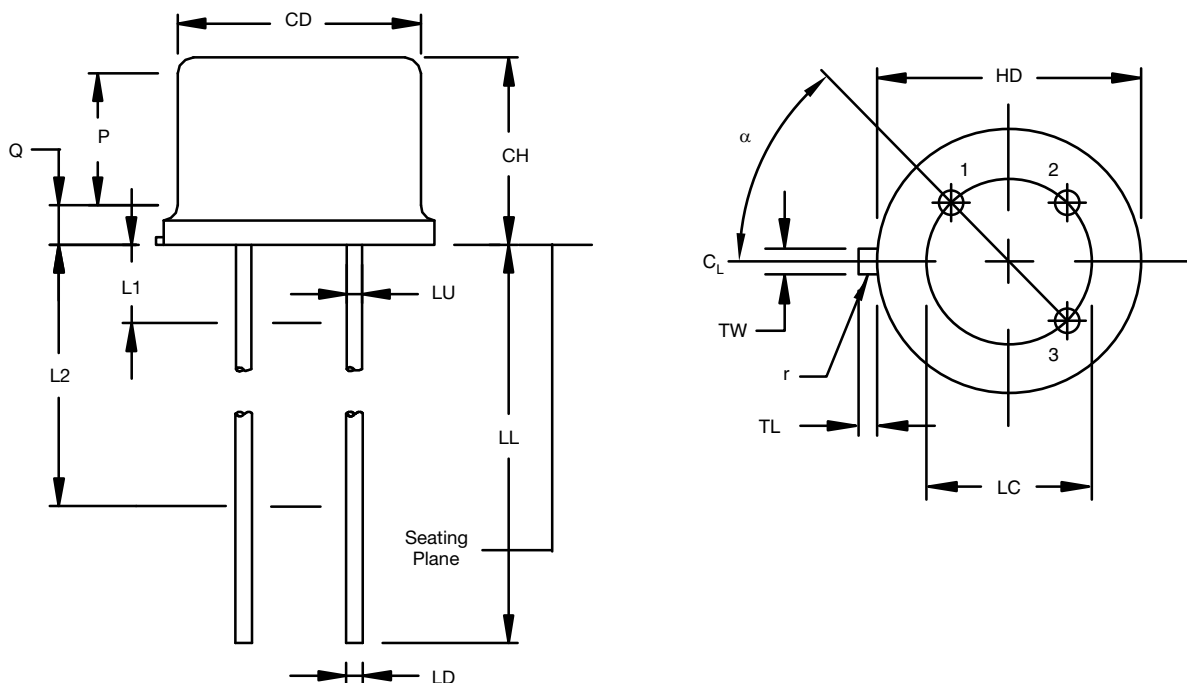
Load Condition Effects on Switching



Normalized Thermal Transient Impedance, Junction-to-Ambient

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TO-205AD (TO-39 TALL LID)



DIM.	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
CD	0.305	0.335	7.75	8.51
CH	0.240	0.260	6.10	6.60
HD	0.335	0.370	8.51	9.40
LC ⁽⁶⁾	0.200 TP		5.08 TP	
LD ⁽⁷⁾⁽⁸⁾	0.016	0.021	0.41	0.53
LL ⁽⁷⁾⁽⁸⁾	0.500	0.750	12.70	19.05
LU ⁽⁷⁾⁽⁸⁾	0.016	0.019	0.41	0.48
L1 ⁽⁷⁾⁽⁸⁾	—	0.050	—	1.27
L2 ⁽⁷⁾⁽⁸⁾	0.250	—	6.35	—
P ⁽⁵⁾	0.100	—	2.54	—
Q ⁽⁴⁾	—	0.050	—	1.27
r ⁽⁹⁾	—	0.010	—	0.25
TL ⁽³⁾	0.029	0.045	0.74	1.14
TW ⁽²⁾	0.028	0.034	0.71	0.86
α ⁽⁶⁾	45° TP		45° TP	
ECN: S15-1675-Rev. D, 27-Jul-15				
DWG: 5511				

Notes

- (1) Dimensions are in inches. Metric equivalents are given for general information only.
- (2) Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011" (0.028 mm).
- (3) Dimension TL measured from maximum HD.
- (4) Outline in this zone is not controlled.
- (5) Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- (6) Leads at gauge plane 0.054" + 0.001", - 0.000" (1.37 mm + 0.03 mm, - 0.00 mm) below seating plane shall be within 0.007" (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- (7) LU applies between L1 and L2, LD applies between L2 and L maximum. Diameter is uncontrolled in L1 and beyond LL minimum.
- (8) All three leads.
- (9) Radius (r) applies to both inside corners of tab.
- (10) Drain is electrically connected to the case.



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